

Excellent Integrated System Limited

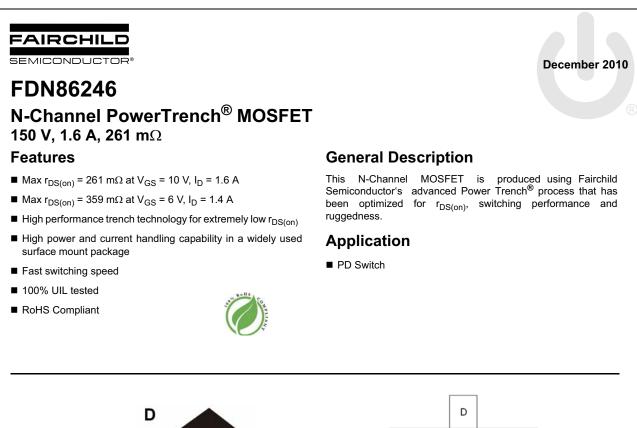
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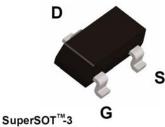
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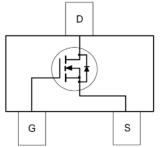
Fairchild Semiconductor FDN86246

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>









MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter		Ratings	Units	
V _{DS}	Drain to Source Voltage		150	V	
V _{GS}	Gate to Source Voltage		±20	V	
I _D	-Continuous (Note 1a)		1.6		
	-Pulsed		6	Α	
E _{AS}	Single Pulse Avalanche Energy	(Note 3)	13	mJ	
P	Power Dissipation	(Note 1a)	1.5		
P _D	Power Dissipation	(Note 1b)	0.6	W	
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C	

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Note 1)	75	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	80	C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
246	FDN86246	SSOT-3	7 "	8 mm	3000 units

FDN86246 N-Channel PowerTrench[®] MOSFET

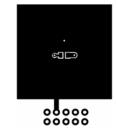


Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	cteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	150			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = 250 µA, referenced to 25 °C		106		mV/°C	
IDSS	Zero Gate Voltage Drain Current	V _{DS} = 120 V, V _{GS} = 0 V			1	μA	
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA	
On Chara	cteristics (Note 2)						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	2	3.4	4	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I _D = 250 μA, referenced to 25 °C		-9		mV/°C	
	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 1.6 A		195	261		
r _{DS(on)}		V _{GS} = 6 V, I _D = 1.4 A		242	359	mΩ	
		V _{GS} = 10 V, I _D = 1.6 A, T _J = 125 °C		359	481	1	
9 _{FS}	Forward Transconductance	V _{DS} = 10 V, I _D = 1.6 A		4		S	
Dynamic	Characteristics						
C _{iss}	Input Capacitance			168	225	pF	
C _{oss}	Output Capacitance	— V _{DS} = 75 V, V _{GS} = 0 V, — f = 1 MHz		21	30	pF	
C _{rss}	Reverse Transfer Capacitance			1.6	5	pF	
R _g	Gate Resistance			0.9		Ω	
Switching	y Characteristics						
t _{d(on)}	Turn-On Delay Time			4.5	10	ns	
t _r	Rise Time	V _{DD} = 75 V, I _D = 1.6 A,		1.1	10	ns	
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10 V, R_{GEN} = 6 Ω		8	16	ns	
t _f	Fall Time			2.9	10	ns	
Q _q	Total Gate Charge	V _{GS} = 0 V to 10 V		2.9	5	nC	
Q _q	Total Gate Charge	$V_{GS} = 0 V \text{ to } 5 V V_{DD} = 75 V,$		1.6	3	nC	
Q _{gs}	Gate to Source Gate Charge	I _D = 1.6 A		0.9		nC	
Q _{gd}	Gate to Drain "Miller" Charge			0.8		nC	

V _{SD}	Source to Drain Diode Forward Voltage	V _{GS} = 0 V, I _S = 1.6 A (Note 2)	0.83	1.3	V
t _{rr}	Reverse Recovery Time	- I _F = 1.6 A, di/dt = 100 A/μs	44	70	ns
Q _{rr}	Reverse Recovery Charge	$F_{\rm F} = 1.6$ Å, di/dt = 100 Å/µs	29	47	nC

Notes:

 $R_{0,LC}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{0,LC}$ is guaranteed by design while R_{0CA} is determined by the user's board design.



a) 80 °C/W when mounted on a 1 in² pad of 2 oz copper



b) 180 °C/W when mounted on a minimum pad.

2. Pulse Test: Pulse Width < 300 μ s, Duty cycle < 2.0%.

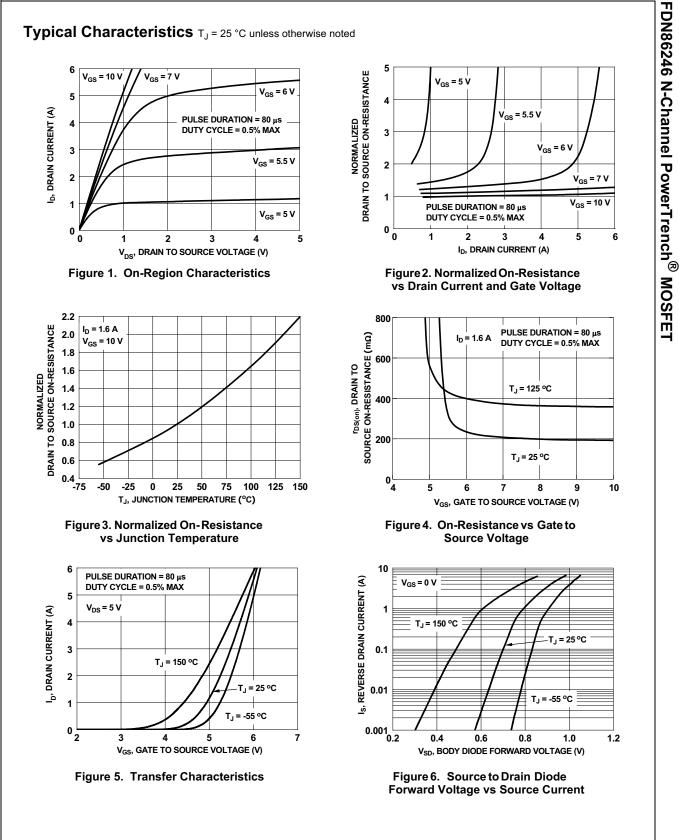
3. Starting T_J = 25 °C; N-ch: L = 3 mH, I_{AS} = 3 A, V_DD = 150 V, V_GS = 10 V.

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FDN86246 N-Channel PowerTrench[®] MOSFET

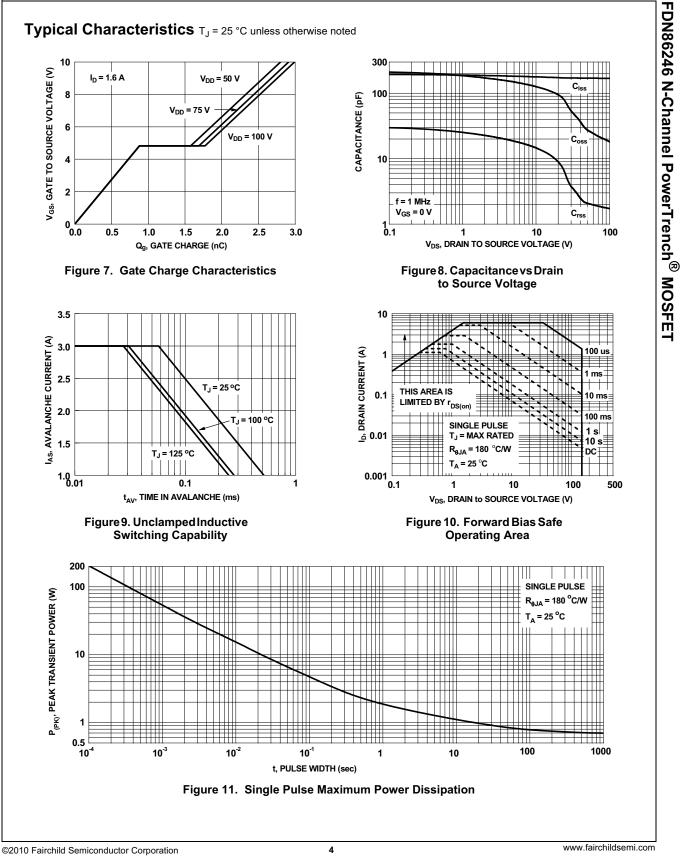




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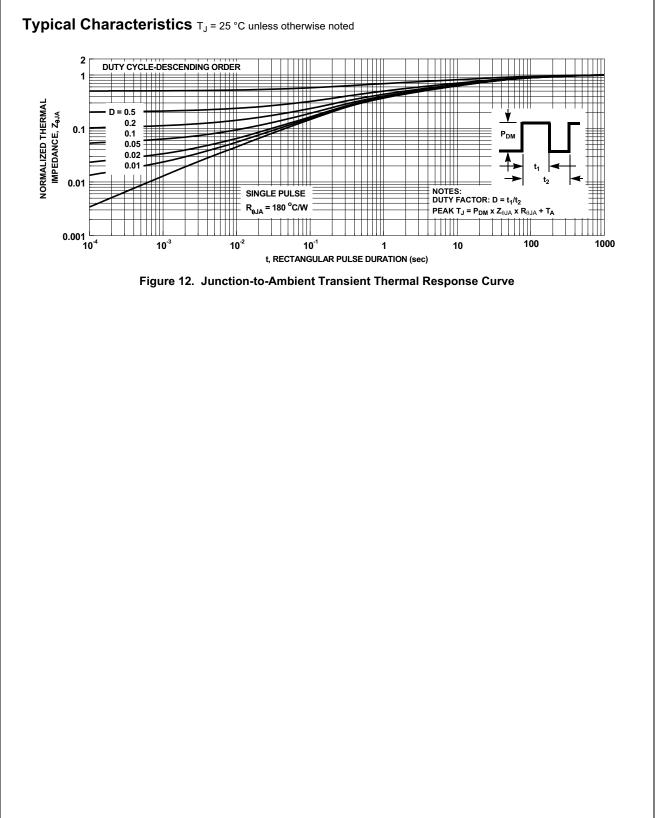
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